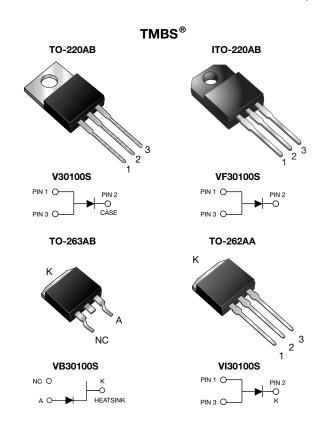


Vishay General Semiconductor

High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.39 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V _{RRM}	100 V					
I _{FSM}	250 A					
V _F at I _F = 30 A	0.69 V					
T _J max.	150 °C					

FEATURES

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

• High efficiency operation

· Low thermal resistance

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	V30100S	VF30100S	VB30100S	VI30100S	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	100			V			
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	30			Α			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	250			А			
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 90 mH	E _{AS}	230			mJ			
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}C \pm 2 ^{\circ}C$	I _{RRM}	1.0			А			
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500		V				
Operating junction and storage temperature range	T _J , T _{STG}	- 40 to + 150			°C			

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 10 mA	T _A = 25 °C	V_{BR}	105 (minimum)	-	V	
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.47	-	V	
	I _F = 10 A			0.55	-		
	I _F = 30 A			0.80	0.91		
	I _F = 5 A	T _A = 125 °C		0.39	-		
	I _F = 10 A			0.49	-		
	I _F = 30 A			0.69	0.78		
Reverse current	V _R = 70 V	T _A = 25 °C	1 (2)	27	-	μA	
		T _A = 125 °C		11	-	mA	
	V _R = 100 V	T _A = 25 °C	I _R ⁽²⁾	70	1000	μA	
		T _A = 125 °C		23	45	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	V30100S	VF30100S	VB30100S	VI30100S	UNIT
Typical thermal resistance	$R_{ heta JC}$	2.0	4.0	2.0	2.0	°C/W

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30100S-E3/4W	1.875	4W	50/tube	Tube			
ITO-220AB	VF30100S-E3/4W	1.805	4W	50/tube	Tube			
TO-263AB	VB30100S-E3/4W	1.380	4W	50/tube	Tube			
TO-263AB	VB30100S-E3/8W	1.380	8W	800/reel	Tape and reel			
TO-262AA	VI30100S-E3/4W	1.455	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

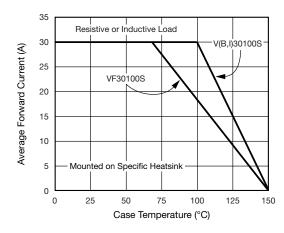


Fig. 1 - Forward Current Derating Curve

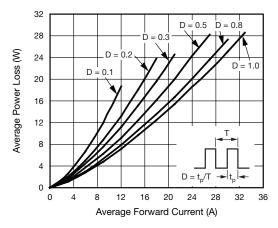


Fig. 2 - Forward Power Loss Characteristics



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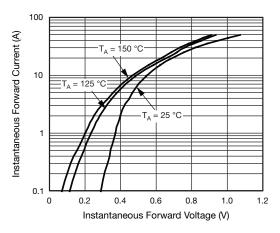


Fig. 3 - Typical Instantaneous Forward Characteristics

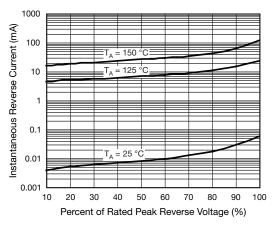


Fig. 4 - Typical Reverse Characteristics

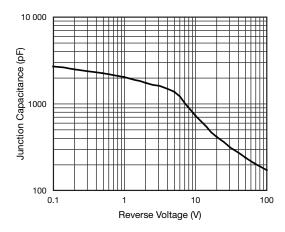


Fig. 5 - Typical Junction Capacitance

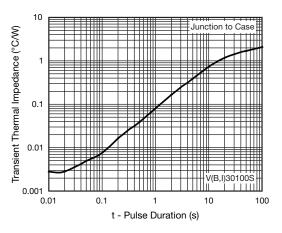


Fig. 6 - Typical Transient Thermal Impedance

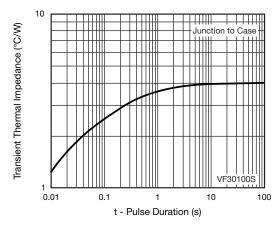
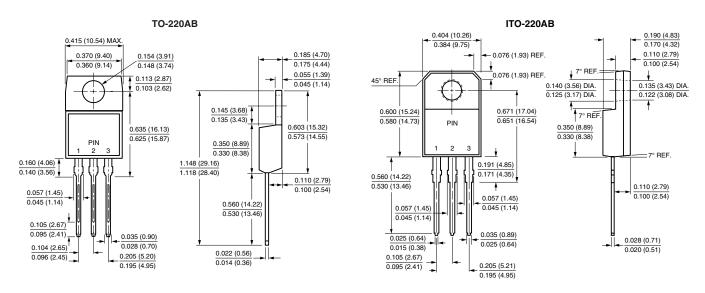


Fig. 7 - Typical Transient Thermal Impedance

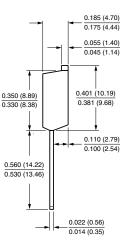
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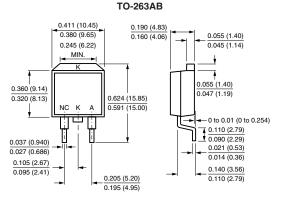


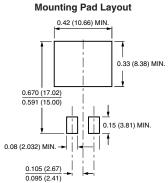
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA 0.411 (10.45) MAX. 0.250 (6.35) MIN 0.055 (1.40) 30° (TYP.) 0.047 (1.19) 0.950 (24.13) 0.510 (12.95) 0.920 (23.37) PIN 0.470 (11.94) 2 0.160 (4.06) 0.140 (3.56) 0.057 (1.45) 0.035 (0.90) 0.028 (0.70) 0.104 (2.65) 0.096 (2.45) 0.205 (5.20) 0.195 (4.95)









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